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Application Information

Title Line One: Silicon Wafer and Method For Manufacture Thereof,

Title Line Two: and Method for Evaluation of Silicon Wafer

Total Drawing Sheets: 14
Formal Drawings: Yes
Application Type: Utility
Docket Number: 86397

Representative Information

Registration Number One: 24,003
Registration Number Two: 22,839
Registration Number Three: 28,903
Registration Number Four: 27,429
Registration Number Five: 25,060
Registration Number Six: 22,053



Registration Number Seven: 27,466 Registration Number Eight: 29,434 Registration Number Nine: 29,054 Registration Number Ten: 29,381 Registration Number Eleven: 34,044 Registration Number Twelve: 27,600 Registration Number Thirteen: 34,137 Registration Number Fourteen: 39,724 Registration Number Fifteen: 37,963 Registration Number Sixteen: 41,050 Registration Number Seventeen: 34,217

This application is based on application

Application One: PCT/JP00/05738

Filing Date: August 25, 2000

which is based on priority document

Japanese application no. 241186/1999

Filing Date: August 27, 1999